## NSN 5961-01-252-0268

No Fiig: A110a0

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-252-0268 **Inclosure Material:** Metal **Overall Length:** 0.185 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.370 inches **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 30.0 collector to base voltage/static/emitter open all transistor and 30.0 collector to emitter voltage/static/base open all transistor and 3.0 emitter to base voltage, static, collector open all transistor **Current Rating Per Characteristic:** 30.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 200.0 milliwatts small-signal input power, common-collector preset all transistor **Transfer Ratio:** 30.0 static forward current transfer ratio, common-emitter all transistor and 165.0 static forward current transfer ratio, common-emitter all transistor **Special Features:** All transistor junction pattern arrangement: pnp **Terminal Type And Quantity:** 6 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**